

Am2847 • Am2896

Quad 80-Bit and Quad 96-Bit Static Shift Registers

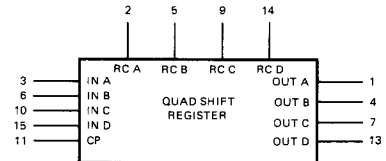
Distinctive Characteristics

- Plug-in replacement for 2532B, TMS3120, TMS 3409, MK1007, 3347
- Internal recirculates on each register
- Single TTL compatible clock
- Outputs sink two TTL loads
- Operation guaranteed from DC to 3 MHz
- 100% reliability assurance testing in compliance with MIL-STD-883

FUNCTIONAL DESCRIPTION

The Am2847 and Am2896 are quad 80-and 96-bit static MOS shift registers. Each device contains four shift registers, each with a TTL compatible input, output, and recirculate control. When the RC signal is LOW, the corresponding register accepts data from its data input; when RC is HIGH, the data at the register output is written back in at the input. The four registers are driven by a common TTL compatible clock input. The registers shift on the HIGH-to-LOW transition of the clock. Storage is dynamic while the clock is HIGH and static while the clock is LOW, so the clock may be stopped indefinitely in the LOW state. Each register output can drive two TTL unit loads.

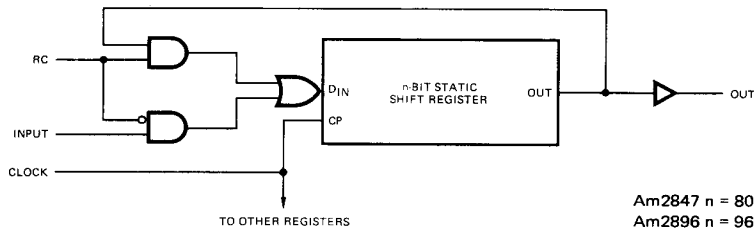
LOGIC SYMBOL



V_{SS} = Pin 16
V_{DD} = Pin 8
V_{GG} = Pin 12

MOS-435

LOGIC BLOCK DIAGRAM (One Register Shown)



Am2847 n = 80
Am2896 n = 96

MOS-436

ORDERING INFORMATION

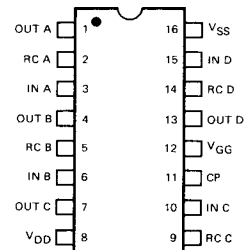
Am2847 Quad 80-Bit

Package Type	Temperature Range	Order Number
16-Pin Molded DIP	0°C to +70°C	AM2847PC
16-Pin Hermetic DIP	0°C to +70°C	AM2847DC
16-Pin Hermetic DIP	-55°C to +125°C	AM2847DM

Am2896 Quad 96-Bit

16-Pin Molded DIP	0°C to +70°C	AM2896PC
16-Pin Hermetic DIP	0°C to +70°C	AM2896DC
16-Pin Hermetic DIP	-55°C to +125°C	AM2896DM

CONNECTION DIAGRAM Top View



Note: Pin 1 is marked for orientation.

MOS-437

MAXIMUM RATINGS (Above which the useful life may be impaired)

Storage Temperature	−65°C to +160°C
Temperature (Ambient) Under Bias	−55°C to +125°C
V _{DD} Supply Voltage	V _{SS} −10V to V _{SS} +0.3V
V _{GG} Supply Voltage	V _{SS} −20V to V _{SS} +0.3V
DC Input Voltage	V _{SS} −20V to V _{SS} +0.3V

OPERATING RANGE

Part Number	Ambient Temperature	V _{SS}	V _{DD}	V _{GG}
Am2847DM Am2896DM	−55°C to +125°C	5.0V ±5%	0V	−12V ±5%
Am2847PC, DC Am2896PC, DC.	0°C to +70°C	5.0V ±5%	0V	−12V ±5%

ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE (Unless Otherwise Noted)

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Parameters	Description	Test Conditions		Min.	Typ. (Note 1)	Max.	Units
V _{OH}	Output HIGH Voltage	I _{OH} = −0.5mA		2.4			Volts
V _{OL}	Output LOW Voltage	I _{OL} = 3.2mA 0°C to 70°C				0.4	Volts
		I _{OL} = 2.4mA −55° to 125°C					
V _{IH}	Input HIGH Level	Guaranteed input logical HIGH voltage for all inputs		V _{SS} −1.0		V _{SS} +0.3	Volts
V _{IL}	Input LOW Level	Guaranteed input logical LOW voltage for all inputs		V _{SS} −18.5		0.8	Volts
I _{LI}	Input Leakage Current	V _{IN} = −5.0V, all other pins connected to V _{SS}				1.0	μA
I _{IL}	Input LOW Current	V _{IN} = 0.4V			−1.0	−1.6	mA
I _{IH}	Input HIGH Current	V _{IN} = V _{SS} −1.0V		−0.1			mA
I _{DD}	V _{DD} Power Supply Current	Output open, f = 2.5MHz	0°C to 70°C		25	35	mA
			−55°C to 125°C			45	
I _{GG}	V _{GG} Power Supply Current		0°C to 70°C		10	15	
			−55°C to 125°C			20	

Note: 1. Typical Limits are at V_{SS} = 5.0V, V_{GG} = −12V, 25°C ambient.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE (Unless Otherwise Noted)

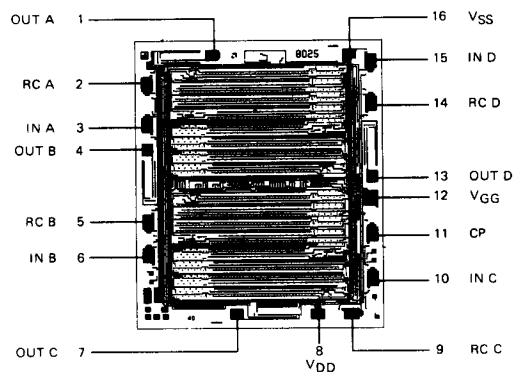
Parameters	Description	Test Conditions	Min.	Typ.	Max.	Units
f	Clock Frequency	0°C to 70°C	0		3.0	MHz
		−55°C to 125°C			2.5	
t _{φpwH}	Clock HIGH Time	0°C to 70°C	.140		100	μs
		−55°C to 125°C	.150		10	
t _{φpwL}	Clock LOW Time	0°C to 70°C	.140		∞	μs
		−55°C to 125°C	.180			
t _r , t _f	Clock Rise and Fall Times		10		200	ns
t _s	Set-Up Time, D or RC Inputs (see definitions)	t _r = t _f = 10ns	0°C to 70°C			ns
			−55°C to 125°C		120	
t _h	Hold Time, D or RC Inputs (see definitions)	t _r = t _f = 10ns	0°C to 70°C		40	ns
			−55°C to 125°C		60	
t _{pd}	Delay, Clock to Output LOW or HIGH	R _L = 4k, C _L = 10pF	0°C to 70°C	(Note 3)	200	ns
			−55°C to 125°C		280	
C _{in}	Capacitance, Data Clock and RC Inputs (Note 2)	f = 1MHz, V _{IN} = V _{SS}		3.0	7.0	pF
C _φ	Capacitance, Clock Input (Note 2)	f = 1MHz, V _{IN} = V _{SS}		3.0	7.0	pF

Notes: 2. This parameter is periodically sampled but not 100% tested. It is guaranteed by design.

3. At any temperature, t_{pd} min. is always much greater than t_h (D) max.

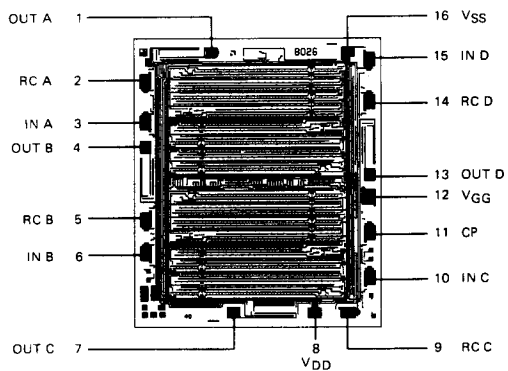
Metallization and Pad Layouts

Am2847



DIE SIZE 0.106" X 0.128"

Am2896



DIE SIZE 0.106" X 0.128"

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